

SPTECH Silicon NPN Power Transistor

2SC2334

DESCRIPTION

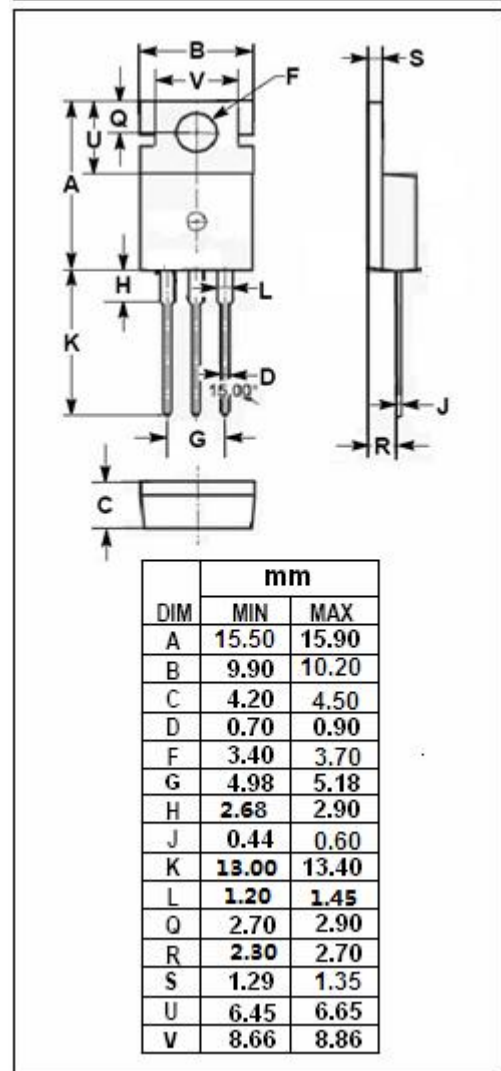
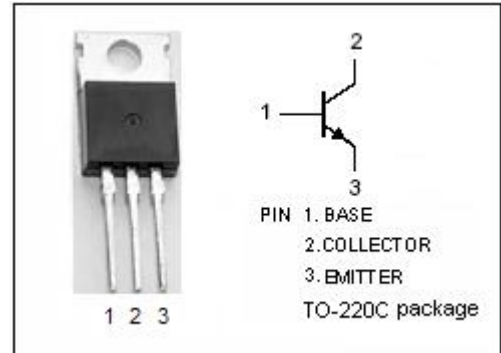
- Low Collector Saturation Voltage
- Fast Switching Speed
- Complement to Type 2SA1010

APPLICATIONS

- Developed for high-voltage high-speed switching, and is ideal for use as a driver in devices such as switching regulators, DC/DC converters, and high frequency power amplifiers.

ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|--|---------|------|
| V _{CBO} | Collector-Base Voltage | 150 | V |
| V _{CEO} | Collector-Emitter Voltage | 100 | V |
| V _{EBO} | Emitter-Base Voltage | 7.0 | V |
| I _C | Collector Current-Continuous | 7.0 | A |
| I _{CM} | Collector Current-Peak | 15 | A |
| I _B | Base Current-Continuous | 3.5 | A |
| P _C | Collector Power Dissipation @ T _a =25°C | 1.5 | W |
| | Total Power Dissipation @ T _C =25°C | 40 | |
| T _J | Junction Temperature | 150 | °C |
| T _{stg} | Storage Temperature Range | -55~150 | °C |



ELECTRICAL CHARACTERISTICS

T_c=25°C unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | MAX | UNIT |
|-----------------------|--------------------------------------|---|-----|-----------|-----------|
| V _{CEO(SUS)} | Collector-Emitter Sustaining Voltage | I _C = 50mA ; I _B = 0 | 100 | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 5.0A; I _B = 0.5A | | 0.6 | V |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | I _C = 5.0A; I _B = 0.5A | | 1.5 | V |
| I _{CBO} | Collector Cutoff Current | V _{CB} = 100V ; I _E = 0 | | 10 | μ A |
| I _{CER} | Collector Cutoff Current | V _{CE} = 100V ; R _{BE} = 51 Ω , T _a =125°C | | 1.0 | mA |
| I _{CEx} | Collector Cutoff Current | V _{CE} = 100V; V _{BE(off)} = -1.5V V _{CE} = 100V; V _{BE(off)} = -1.5V, T _a =125°C | | 10 1.0 | μ A mA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = 5V; I _C = 0 | | 10 | μ A |
| h _{FE-1} | DC Current Gain | I _C = 0.5A ; V _{CE} = 5V | 40 | | |
| h _{FE-2} | DC Current Gain | I _C = 3.0A ; V _{CE} = 5V | 40 | 200 | |
| h _{FE-3} | DC Current Gain | I _C = 5.0A ; V _{CE} = 5V | 20 | | |

Switching times

| | | | | | |
|------------------|--------------|---|--|-----|-----|
| t _{on} | Turn-on Time | I _C = 5.0A , R _L = 10 Ω , I _{B1} = -I _{B2} = 0.5A, V _{CC} ≈ 50V | | 0.5 | μ s |
| t _{stg} | Storage Time | | | 1.5 | μ s |
| t _f | Fall Time | | | 0.5 | μ s |

◆ **h_{FE-2} Classifications**

| M | L | K |
|-------|--------|---------|
| 40-80 | 60-120 | 100-200 |